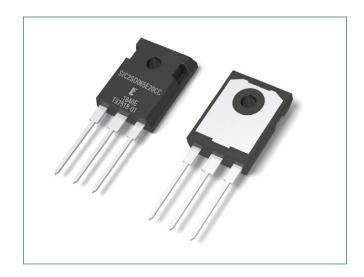


# LSIC2SD065E20CCA 650 V, 20 A SiC Schottky Barrier Diode







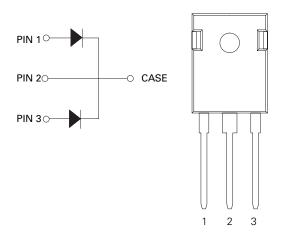
#### **Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### **Features**

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C. maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

#### Circuit Diagram TO-247-3L



### **Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- · Industrial motor drives
- EV charging stations

#### **Environmental**

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating



### **Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	650	V	
DC Blocking Voltage	$V_R$	T <sub>J</sub> = 25 °C	650	V	
Continuous Forward Current (Per Leg/Component)		T <sub>C</sub> = 25 °C	27 / 54	A	
	I <sub>F</sub>	T <sub>C</sub> = 147 °C	10 / 20		
Non-Repetitive Forward Surge Current (Per Leg)	I <sub>FSM</sub>	$T_{\rm C}$ = 25 °C, $t_{\rm p}$ = 10 ms, Half sine pulse	50	А	
Power Dissipation (Per Leg/Component)	D	T <sub>C</sub> = 25 °C	100 / 200	W	
	P <sub>Tot</sub>	T <sub>C</sub> = 110 °C	43 / 86	V V	
Operating Junction Temperature	T <sub>J</sub>	-	-55 to 175	°C	
Storage Temperature	T <sub>STG</sub>	-	-55 to 150	°C	
Soldering Temperature	T <sub>sold</sub>	-	260	°C	

# **GEN2 SiC Schottky Diode**

LSIC2SD065E20CCA, 650 V, 20 A, T0-247-3L

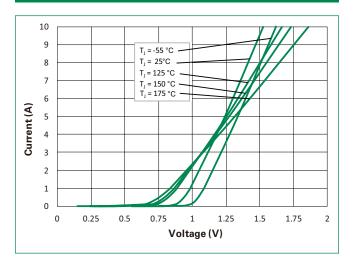
# Electrical Characteristics (T<sub>J</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Conditions	Value			11.56	
Characteristics			Min.	Тур.	Max.	Unit	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 A, T <sub>J</sub> = 25 °C	-	1.5	1.8	V	
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 175 °C	-	1.85	-		
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 650 V, T <sub>J</sub> = 25 °C	-	<1	50	μΑ	
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 175 °C	-	25	-		
Total Capacitance	С	$V_R = 1 V$ , $f = 1 MHz$	-	470	-		
		V <sub>R</sub> = 200 V, f = 1 MHz	-	60	-	pF	
		V <sub>R</sub> = 400 V, f = 1 MHz	-	43	-		
Total Capacitive Charge	Q <sub>c</sub>	$V_{R} = 400 \text{ V}, \ Q_{c} = \int_{0}^{V_{R}} C(V) dV$	-	30	-	nC	

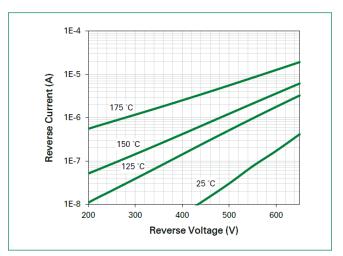
#### **Thermal Characteristics**

Characteristics	Symbol Value		Unit
Thermal Resistance (Per Leg/Component)	R <sub>euc</sub>	1.50 / 0.75	°C/W

# **Figure 1: Typical Foward Characteristics**



# **Figure 2: Typical Reverse Characteristics**





**Figure 3: Power Derating** 

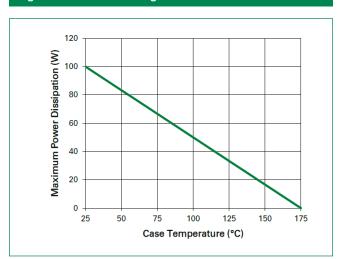


Figure 4: Current Derating

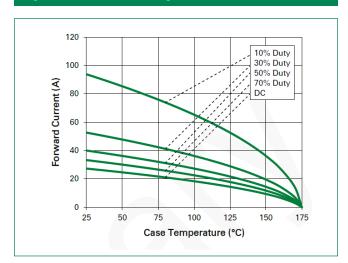


Figure 5: Capacitance vs. Reverse Voltage

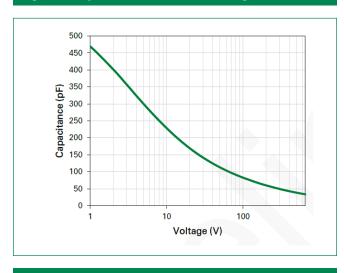


Figure 6: Capacitive Charge vs. Reverse Voltage

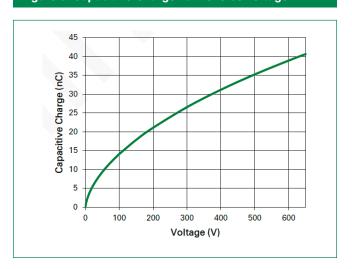
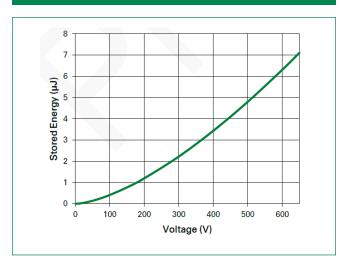
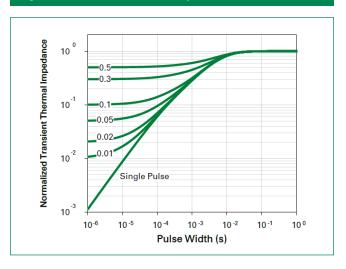


Figure 7: Stored Energy vs. Reverse Voltage



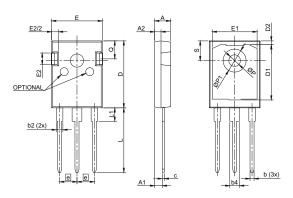
**Figure 8: Transient Thermal Impedance** 



# **GEN2 SiC Schottky Diode**

LSIC2SD065E20CCA, 650 V, 20 A, T0-247-3L

# Package Dimensions TO-247-3L





- Notes:

  1. Dimensions are in millimeters

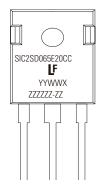
  2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.

  3.eP to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 0.154°

Symbol	Millimeters				
Symbol .	Min	Nom	Max		
Α	4.80	5.03	5.20		
A1	2.25	2.38	2.54		
A2	1.85	1.98	2.11		
b	0.99	-	1.40		
b2	1.65	-	2.39		
b4	2.59	-	3.43		
С	0.38	0.64	0.89		
D	20.80	20.96	21.34		
D1	13.50	-	-		
D2	0.51	1.19	1.35		
е	5.44 BSC				
E	15.75	15.90	16.13		
E1	13.06	14.02	14.15		
E2	4.19	4.32	4.83		
L	19.81	20.19	20.57		
L1	3.81	4.19	4.45		
øΡ	3.55	3.61	3.66		
øP1	7.06	7.19	7.32		
Q	5.49	5.61	6.20		
S	6.05	6.17	6.30		

# **Part Numbering and Marking System**

WW



SIC	= SiC
2	= Gen2
SD	= Schottky Diode
065	= Voltage Rating (650 V)
E	= T0-247-3L
20	= Current Rating (20 A)
CC	= Common Cathode
YY	= Year

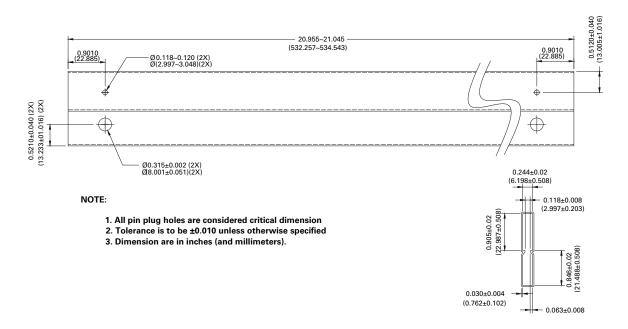
= Week = Trace Code (Any Letter) 777777-77 = Lot Number

# **Packing Options**

Part Number		Marking	Packing Mode	М.О.О
	LSIC2SD065E20CCA	SIC2SD065E20CC	Tube (30pcs)	450

# GEN2 SiC Schottky Diode LSIC2SD065E20CCA, 650 V, 20 A, TO-247-3L

# **Packing Specification TO-247-3L**



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